

**LOW DROPOUT LINEAR REGULATOR****AZ1117B****General Description**

The AZ1117B is a low dropout three-terminal regulator.

The AZ1117B has been optimized for low voltage where transient response and minimum input voltage are critical. It provides current limit and thermal shutdown. Its circuit includes a trimmed bandgap reference to assure output voltage accuracy to be within $\pm 1\%$. On-chip thermal shutdown provides protection against a combination of high current and ambient temperature that would create excessive junction temperature.

The AZ1117B is available in 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, 5.0V fixed output voltage versions and ADJ output voltage version. The fixed versions integrate the adjust resistors. It is also available in an adjustable version which can set the output voltage with two external resistors.

The AZ1117B is available in the industry-standard SOT-223 and SOT-89 power packages.

Features

- Current Limit: 1.0A (Typ.)
- Output Noise from 10Hz to 10KHz: 0.003% of V_{OUT}
- PSRR at $I_{OUT}=300mA$ and $f=120Hz$: 70dB
- Output Voltage Accuracy: $\pm 1\%$
- On-chip Thermal Shutdown
- Maximum Quiescent Current: $I_{QMAX}=6mA$
- Operation Junction Temperature: -20 to 125°C

Applications

- USB Device
- Add-on Card
- DVD Player
- PC Motherboard

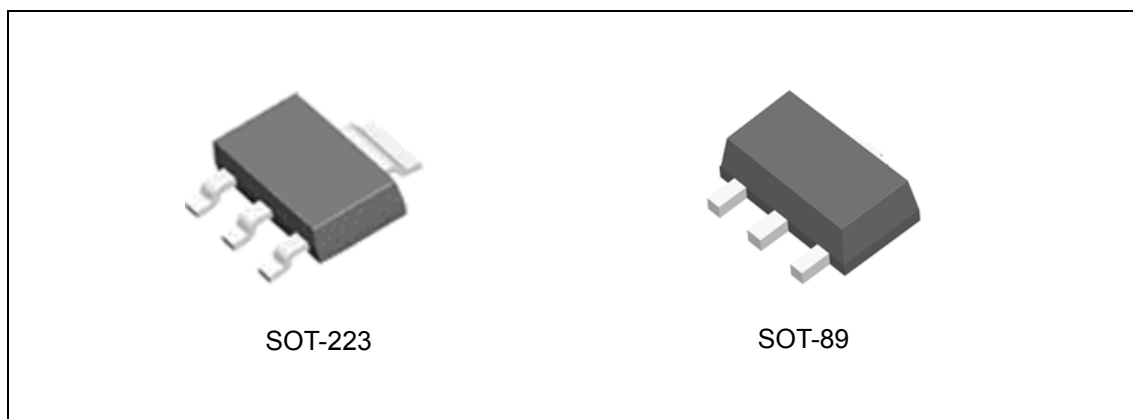


Figure 1. Package Type of AZ1117B



LOW DROPOUT LINEAR REGULATOR

AZ1117B

Pin Configuration



Figure 2. Pin Configuration of AZ1117B (Top View)

Functional Block Diagram

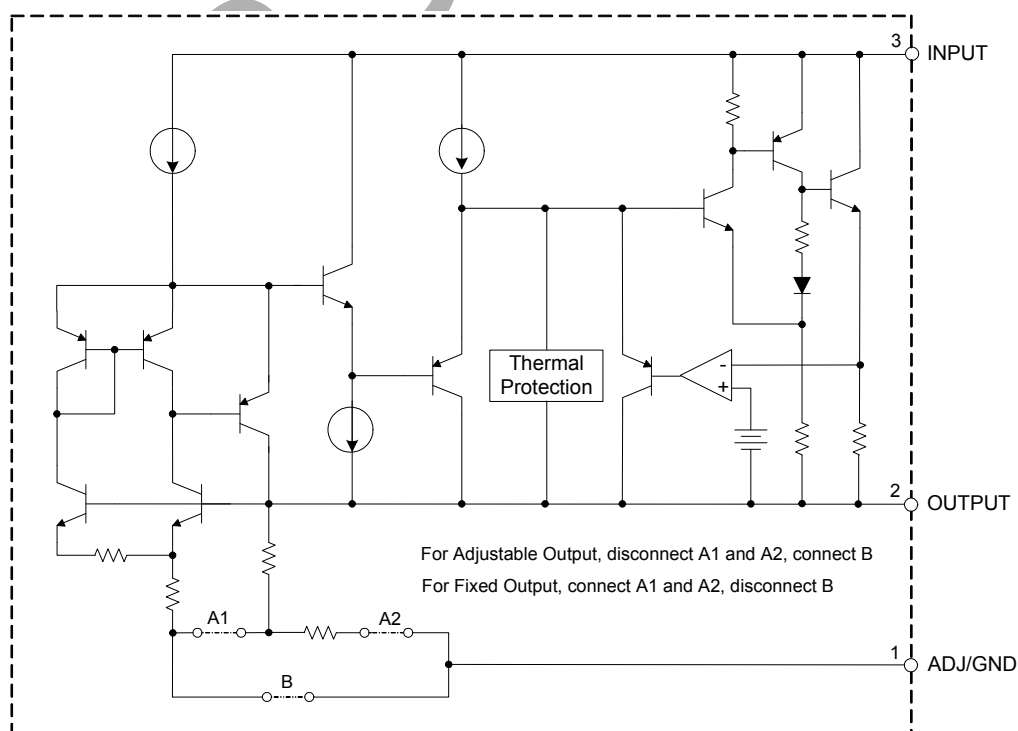
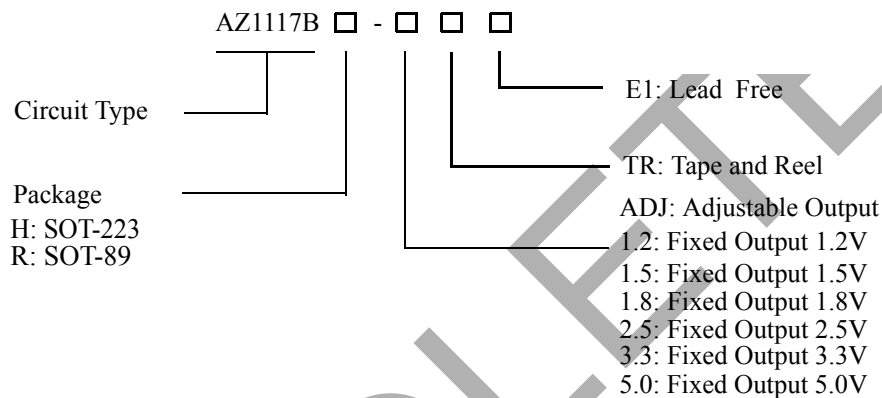


Figure 3. Functional Block Diagram of AZ1117B

**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Ordering Information**

Package	Temperature Range	Part Number	Marking ID	Packing Type
SOT-223	-20 to 125°C	AZ1117BH-ADJTRE1	EH17K	Tape & Reel
		AZ1117BH-1.2TRE1	EH17P	Tape & Reel
		AZ1117BH-1.5TRE1	EH17Q	Tape & Reel
		AZ1117BH-1.8TRE1	EH17L	Tape & Reel
		AZ1117BH-2.5TRE1	EH17N	Tape & Reel
		AZ1117BH-3.3TRE1	EH17M	Tape & Reel
		AZ1117BH-5.0TRE1	EH17R	Tape & Reel
SOT-89	-20 to 125°C	AZ1117BR-ADJTRE1	E31F	Tape & Reel
		AZ1117BR-1.2TRE1	E31G	Tape & Reel
		AZ1117BR-1.5TRE1	E31H	Tape & Reel
		AZ1117BR-1.8TRE1	E31J	Tape & Reel
		AZ1117BR-2.5TRE1	E31K	Tape & Reel
		AZ1117BR-3.3TRE1	E31L	Tape & Reel
		AZ1117BR-5.0TRE1	E31M	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant.

**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value		Unit
Input Voltage	V_{IN}	18		V
Operating Junction Temperature Range	T_J	150		°C
Storage Temperature Range	T_{STG}	-65 to 150		°C
Thermal Resistance (No Heatsink)	θ_{JA}	SOT-223	150	°C/W
		SOT-89	210	
Lead Temperature (Soldering, 10sec)	T_{LEAD}	260		°C

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Input Voltage	V_{IN}		15	V
Operating Junction Temperature Range	T_J	-20	125	°C

**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Electrical Characteristics****AZ1117B-ADJ Electrical Characteristics**

Operating Conditions: $V_{IN}=V_{OUT}+2V$, $I_{OUT}=10mA$, $T_J=25^{\circ}C$, unless otherwise specified. ($P \leq$ maximum power dissipation).

Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, $-20^{\circ}C$ to $125^{\circ}C$.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reference Voltage	V_{REF}		1.238	1.250	1.262	V
		$1.5V \leq V_{IN}-V_{OUT} \leq 10V$	1.225	1.250	1.270	
Line Regulation	V_{RLINE}	$1.5V \leq V_{IN}-V_{OUT} \leq 10V$		0.001	0.1	%
					0.2	
Load Regulation	V_{RLOAD}			0.4	1.0	%
Dropout Voltage	V_{DROP}	$\Delta V_{REF}=1\%$, $I_{OUT}=0.8A$	SOT-223	1.2	1.3	V
			SOT-89	1.2		
Current Limit	I_{LIMIT}		0.85	1	1.15	A
Adjust Pin Current				60	120	μA
Adjust Pin Current Change		$1.5V \leq (V_{IN}-V_{OUT}) \leq 10V$		0.2	5	μA
Minimum Load Current		$1.5V \leq (V_{IN}-V_{OUT}) \leq 10V$		1.7	5	mA
Ripple Rejection	PSRR	$f=120Hz$, $C_{OUT}=22\mu F$ $(V_{IN}-V_{OUT})=3V$, $I_{OUT}=300mA$		70		dB
Temperature Stability				0.5		%
RMS Output Noise (% of V_{OUT})		$T_A=25^{\circ}C$, $10Hz \leq f \leq 10KHz$		0.003		%
Thermal Shutdown		Junction Temperature		160		$^{\circ}C$
Thermal Shutdown Hysteresis				16		$^{\circ}C$
Thermal Resistance	θ_{JC}	SOT-223		33		$^{\circ}C/W$
		SOT-89		39		

**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Electrical Characteristics (Continued)****AZ1117B-1.2 Electrical Characteristics**

Operating Conditions: $V_{IN} \leq 10V$, $I_{OUT} = 10mA$, $T_J = 25^\circ C$, unless otherwise specified. ($P \leq$ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, $-20^\circ C$ to $125^\circ C$.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V_{OUT}		1.176	1.2	1.224	V
		$3.2V \leq V_{IN} \leq 10V$	1.152	1.2	1.228	
Line Regulation	V_{RLINE}	$1.5V \leq V_{IN} - V_{OUT} \leq 10V$		0.5	6	mV
					10	
Load Regulation	V_{RLOAD}			2	15	mV
Dropout Voltage	V_{DROP}	$\Delta V_{OUT} = 1\%$, $I_{OUT} = 0.8A$		1.2	1.3	V
				1.2		
Current Limit	I_{LIMIT}		0.85	1	1.15	A
Quiescent Current	I_Q	$I_{OUT} = 0$		4	6	mA
Ripple Rejection	PSRR	$f = 120Hz$, $C_{OUT} = 22\mu F$ $(V_{IN} - V_{OUT}) = 3V$, $I_{OUT} = 300mA$		70		dB
Temperature Stability				0.5		%
RMS Output Noise (% of V_{OUT})		$T_A = 25^\circ C$, $10Hz \leq f \leq 10KHz$		0.003		%
Thermal Shutdown		Junction Temperature		160		$^\circ C$
Thermal Shutdown Hysteresis				16		$^\circ C$
Thermal Resistance	θ_{JC}	SOT-223		33		$^\circ C/W$
		SOT-89		39		

**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Electrical Characteristics (Continued)****AZ1117B-1.5 Electrical Characteristics**

Operating Conditions: $V_{IN} \leq 10V$, $I_{OUT} = 10mA$, $T_J = 25^\circ C$, unless otherwise specified. ($P \leq$ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, $-20^\circ C$ to $125^\circ C$.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V_{OUT}		1.485	1.5	1.515	V
		$3.5V \leq V_{IN} \leq 10V$	1.470	1.5	1.530	
Line Regulation	V_{RLINE}	$1.5V \leq V_{IN} - V_{OUT} \leq 10V$		0.5	6	mV
					10	
Load Regulation	V_{RLOAD}			2	15	mV
Dropout Voltage	V_{DROP}	$\Delta V_{OUT} = 1\%$, $I_{OUT} = 0.8A$		1.2	1.3	V
				1.2		
Current Limit	I_{LIMIT}		0.85	1	1.15	A
Quiescent Current	I_Q	$I_{OUT} = 0$		4	6	mA
Ripple Rejection	PSRR	$f = 120Hz$, $C_{OUT} = 22\mu F$ $(V_{IN} - V_{OUT}) = 3V$, $I_{OUT} = 300mA$		70		dB
Temperature Stability				0.5		%
RMS Output Noise (% of V_{OUT})		$T_A = 25^\circ C$, $10Hz \leq f \leq 10KHz$		0.003		%
Thermal Shutdown		Junction Temperature		160		$^\circ C$
Thermal Shutdown Hysteresis				16		$^\circ C$
Thermal Resistance	θ_{JC}	SOT-223		33		$^\circ C/W$
		SOT-89		39		

**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Electrical Characteristics (Continued)****AZ1117B-1.8 Electrical Characteristics**

Operating Conditions: $V_{IN} \leq 10V$, $I_{OUT} = 10mA$, $T_J = 25^\circ C$, unless otherwise specified. ($P \leq$ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, $-20^\circ C$ to $125^\circ C$.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V_{OUT}		1.782	1.8	1.818	V
		$3.8V \leq V_{IN} \leq 10V$	1.764	1.8	1.836	
Line Regulation	V_{RLINE}	$1.5V \leq V_{IN} - V_{OUT} \leq 10V$		0.5	6	mV
					10	
Load Regulation	V_{RLOAD}			2	15	mV
Dropout Voltage	V_{DROP}	$\Delta V_{OUT} = 1\%$, $I_{OUT} = 0.8A$		1.2	1.3	V
				1.2		
Current Limit	I_{LIMIT}		0.85	1	1.15	A
Quiescent Current	I_Q	$I_{OUT} = 0$		4	6	mA
Ripple Rejection	PSRR	$f = 120Hz$, $C_{OUT} = 22\mu F$ ($V_{IN} - V_{OUT} = 3V$, $I_{OUT} = 300mA$)		70		dB
Temperature Stability				0.5		%
RMS Output Noise (% of V_{OUT})		$T_A = 25^\circ C$, $10Hz \leq f \leq 10KHz$		0.003		%
Thermal Shutdown		Junction Temperature		160		$^\circ C$
Thermal Shutdown Hysteresis				16		$^\circ C$
Thermal Resistance	θ_{JC}	SOT-223		33		$^\circ C/W$
		SOT-89		39		

**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Electrical Characteristics (Continued)****AZ1117B-2.5 Electrical Characteristics**

Operating Conditions: $V_{IN} \leq 10V$, $I_{OUT} = 10mA$, $T_J = 25^\circ C$, unless otherwise specified. ($P \leq$ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, $-20^\circ C$ to $125^\circ C$.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V_{OUT}		2.475	2.5	2.525	V
		$4.5V \leq V_{IN} \leq 10V$	2.455	2.5	2.545	
Line Regulation	V_{RLINE}	$1.5V \leq V_{IN} - V_{OUT} \leq 10V$		0.5	6	mV
					10	
Load Regulation	V_{RLOAD}			2	15	mV
Dropout Voltage	V_{DROP}	$\Delta V_{OUT} = 1\%$, $I_{OUT} = 0.8A$		1.2	1.3	V
		SOT-223 SOT-89		1.2		
Current Limit	I_{LIMIT}		0.85	1	1.15	A
Quiescent Current	I_Q	$I_{OUT} = 0$		4	6	mA
Ripple Rejection	PSRR	$f = 120Hz$, $C_{OUT} = 22\mu F$ ($V_{IN} - V_{OUT} = 3V$, $I_{OUT} = 300mA$)		70		dB
Temperature Stability				0.5		%
RMS Output Noise (% of V_{OUT})		$T_A = 25^\circ C$, $10Hz \leq f \leq 10KHz$		0.003		%
Thermal Shutdown		Junction Temperature		160		$^\circ C$
Thermal Shutdown Hysteresis				16		$^\circ C$
Thermal Resistance	θ_{JC}	SOT-223		33		$^\circ C/W$
		SOT-89		39		

**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Electrical Characteristics (Continued)****AZ1117B-3.3 Electrical Characteristics**

Operating Conditions: $V_{IN} \leq 10V$, $I_{OUT} = 10mA$, $T_J = 25^\circ C$, unless otherwise specified. ($P \leq$ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, $-20^\circ C$ to $125^\circ C$.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V_{OUT}		3.267	3.3	3.333	V
		$5.3V \leq V_{IN} \leq 10V$	3.235	3.3	3.365	
Line Regulation	V_{RLINE}	$1.5V \leq V_{IN} - V_{OUT} \leq 10V$		0.5	6	mV
					10	
Load Regulation	V_{RLOAD}			2	15	mV
Dropout Voltage	V_{DROP}	$\Delta V_{OUT} = 1\%$, $I_{OUT} = 0.8A$		1.2	1.3	V
				1.2		
Current Limit	I_{LIMIT}		0.85	1	1.15	A
Quiescent Current	I_Q	$I_{OUT} = 0$		4	6	mA
Ripple Rejection	PSRR	$f = 120Hz$, $C_{OUT} = 22\mu F$ $(V_{IN} - V_{OUT}) = 3V$, $I_{OUT} = 300mA$		70		dB
Temperature Stability				0.5		%
RMS Output Noise (% of V_{OUT})		$T_A = 25^\circ C$, $10Hz \leq f \leq 10KHz$		0.003		%
Thermal Shutdown		Junction Temperature		160		$^\circ C$
Thermal Shutdown Hysteresis				16		$^\circ C$
Thermal Resistance	θ_{JC}	SOT-223		33		$^\circ C/W$
		SOT-89		39		

**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Electrical Characteristics (Continued)****AZ1117B-5.0 Electrical Characteristics**

Operating Conditions: $V_{IN} \leq 10V$, $I_{OUT} = 10mA$, $T_J = 25^\circ C$, unless otherwise specified. ($P \leq$ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, $-20^\circ C$ to $125^\circ C$.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V_{OUT}		4.950	5.0	5.050	V
		$6.5V \leq V_{IN} \leq 10V$	4.900	5.0	5.100	
Line Regulation	V_{RLINE}	$1.5V \leq V_{IN} - V_{OUT} \leq 10V$		0.5	6	mV
					10	
Load Regulation	V_{RLOAD}			2	15	mV
Dropout Voltage	V_{DROP}	$\Delta V_{OUT} = 1\%$, $I_{OUT} = 0.8A$		1.2	1.3	V
		SOT-223 SOT-89		1.2		
Current Limit	I_{LIMIT}		0.85	1	1.15	A
Quiescent Current	I_Q	$I_{OUT} = 0$		4	6	mA
Ripple Rejection	PSRR	$f = 120Hz$, $C_{OUT} = 22\mu F$ $(V_{IN} - V_{OUT}) = 3V$, $I_{OUT} = 300mA$		70		dB
Temperature Stability				0.5		%
RMS Output Noise (% of V_{OUT})		$T_A = 25^\circ C$, $10Hz \leq f \leq 10KHz$		0.003		%
Thermal Shutdown		Junction Temperature		160		$^\circ C$
Thermal Shutdown Hysteresis				16		$^\circ C$
Thermal Resistance	θ_{JC}	SOT-223		33		$^\circ C/W$
		SOT-89		39		



LOW DROPOUT LINEAR REGULATOR

AZ1117B

Typical Performance Characteristics

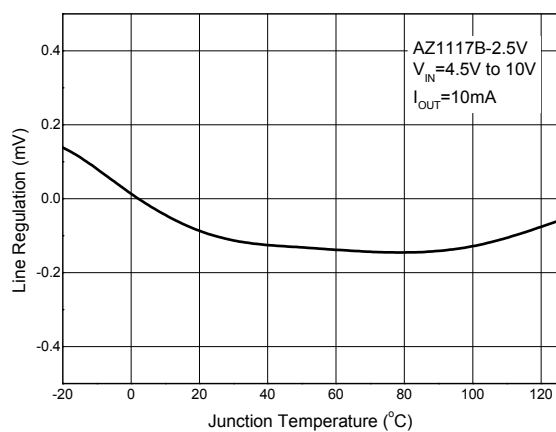


Figure 4. Line Regulation vs. Junction Temperature

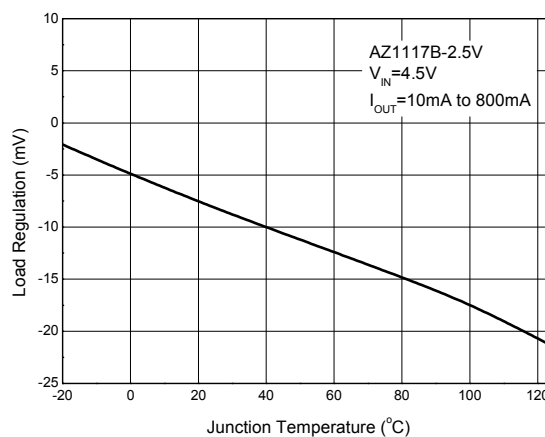


Figure 5. Load Regulation vs. Junction Temperature

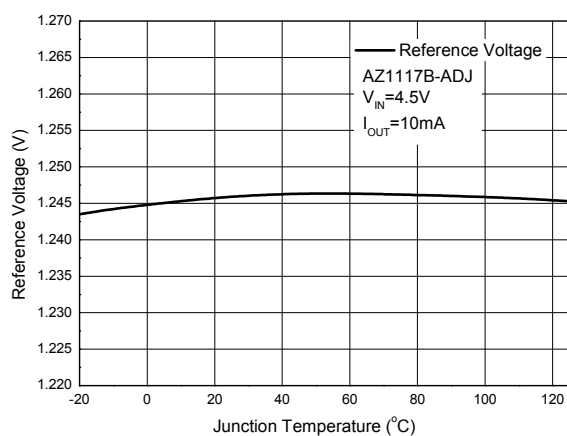


Figure 6. Reference Voltage vs. Junction Temperature

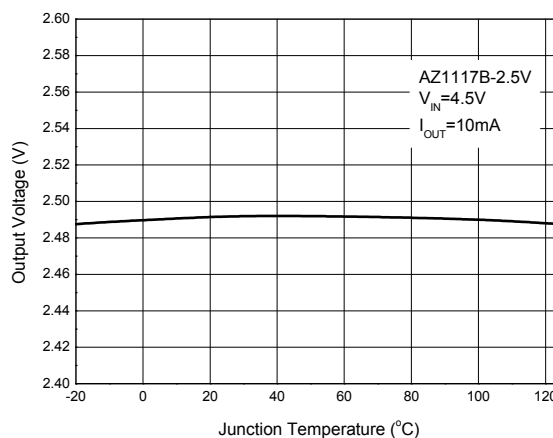


Figure 7. Output Voltage vs. Junction Temperature

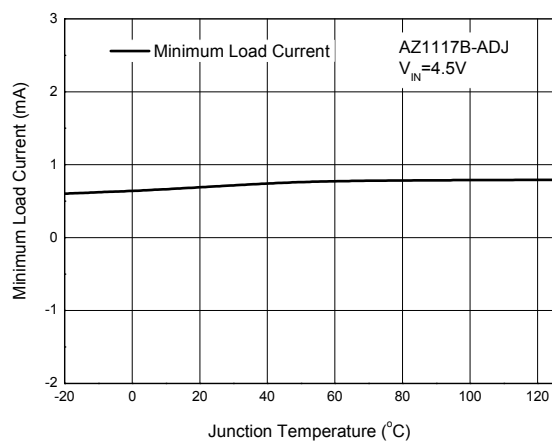
**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Typical Performance Characteristics (Continued)**

Figure 8. Minimum Load Current vs. Junction Temperature

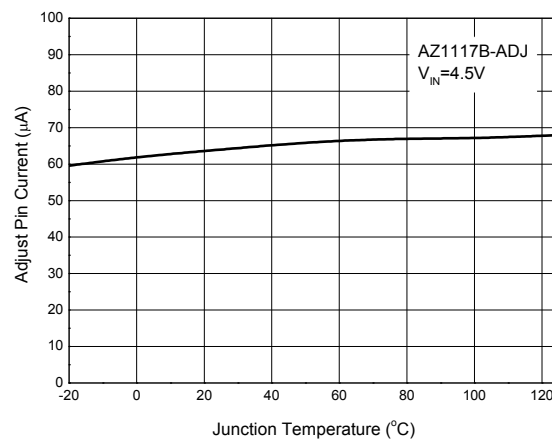


Figure 9. Adjust Pin Current vs. Junction Temperature

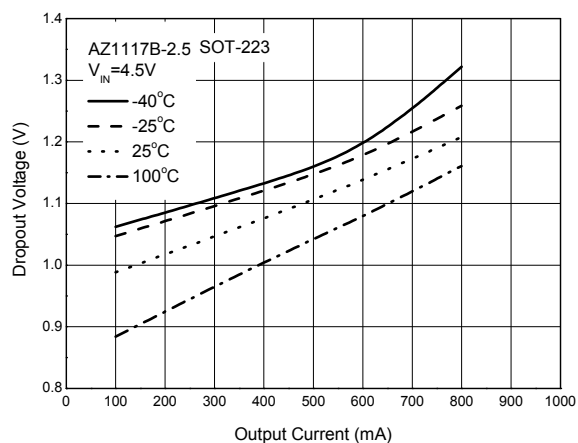


Figure 10. Dropout Voltage vs. Output Current

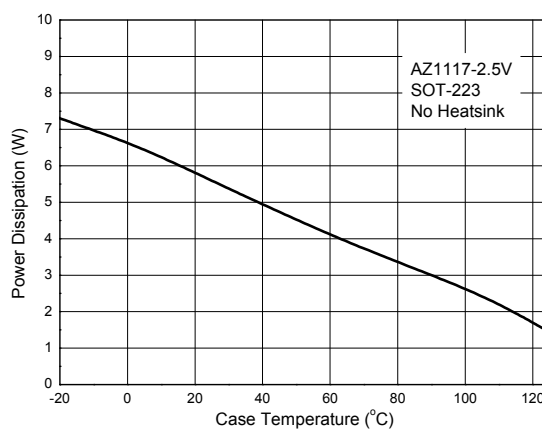


Figure 11. Power Dissipation vs. Case Temperature



LOW DROPOUT LINEAR REGULATOR

AZ1117B

Typical Performance Characteristics (Continued)

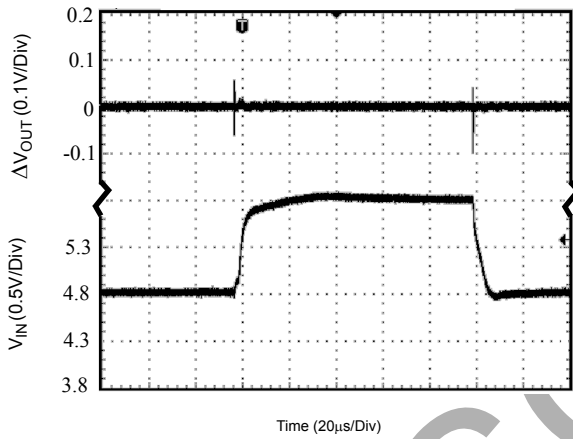


Figure 12. Line Transient Response

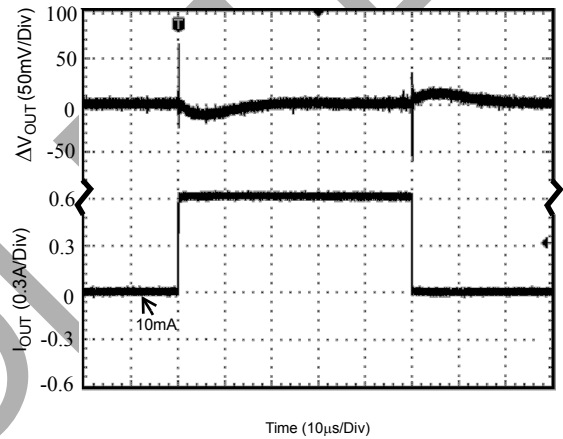


Figure 13. Load Transient Response

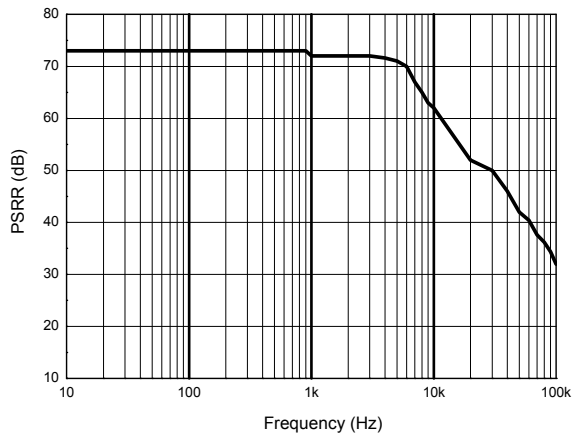


Figure 14. PSRR vs. Frequency

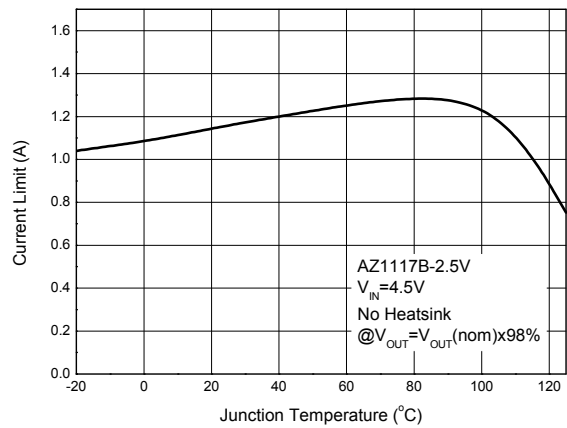


Figure 15. Current Limit vs. Junction Temperature

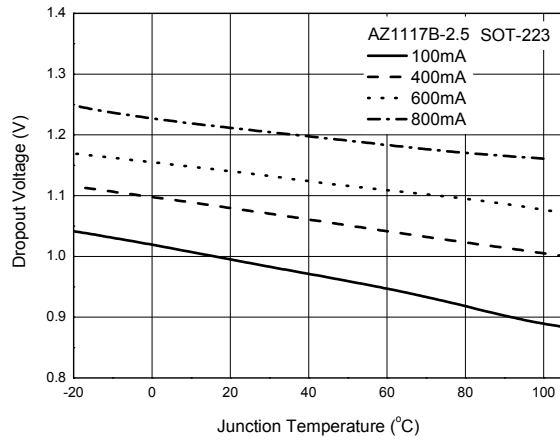
**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Typical Performance Characteristics (Continued)**

Figure 16. Dropout Voltage vs. Junction Temperature



LOW DROPOUT LINEAR REGULATOR

AZ1117B

Typical Applications

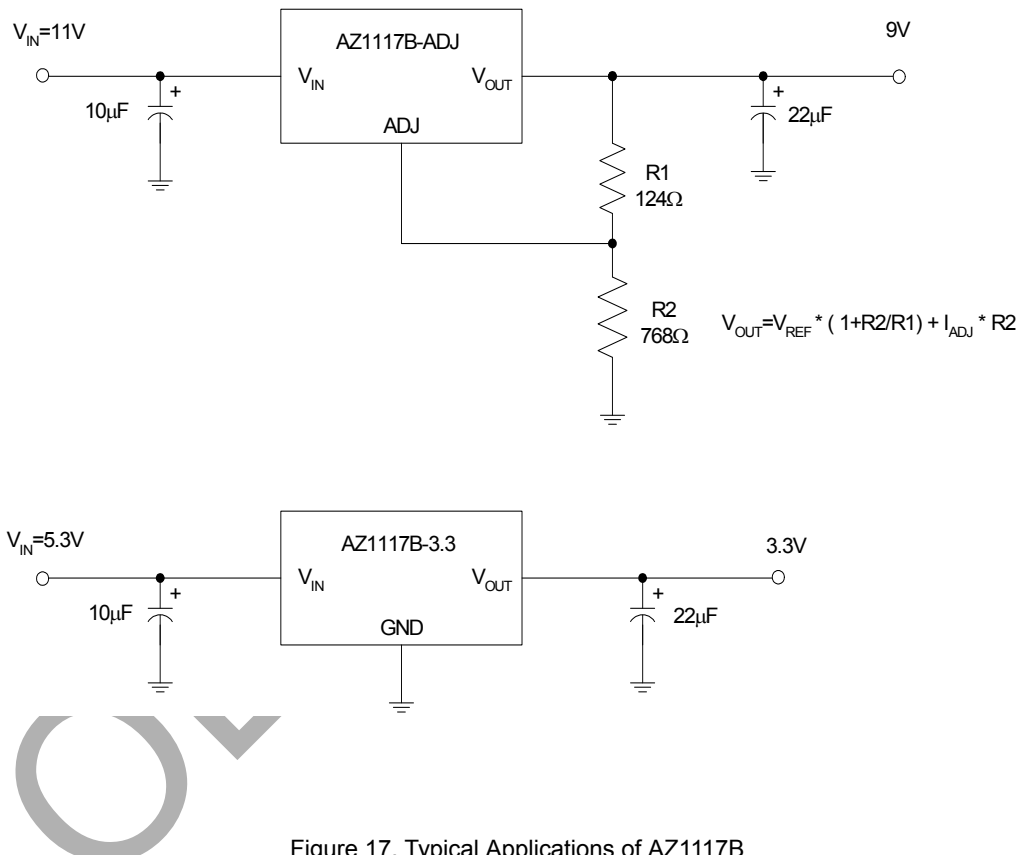


Figure 17. Typical Applications of AZ1117B



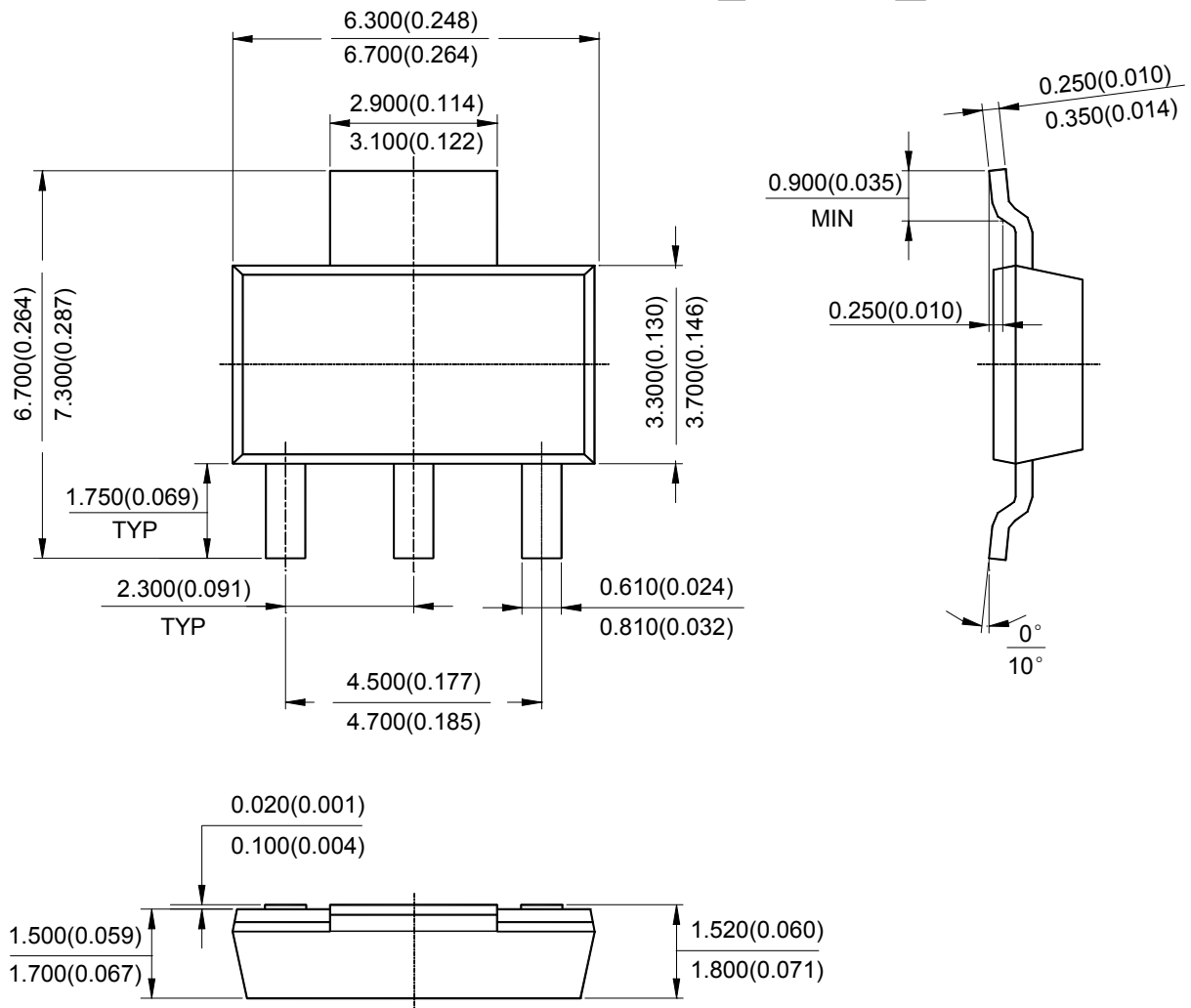
LOW DROPOUT LINEAR REGULATOR

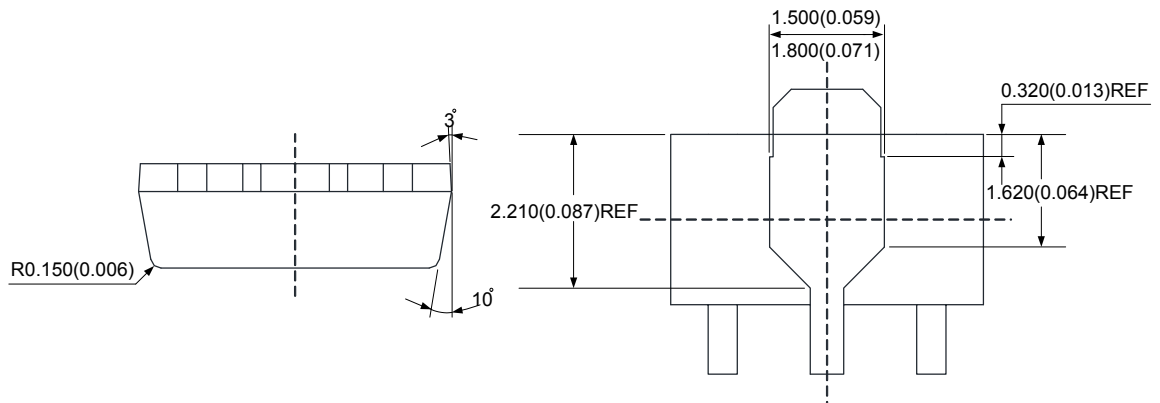
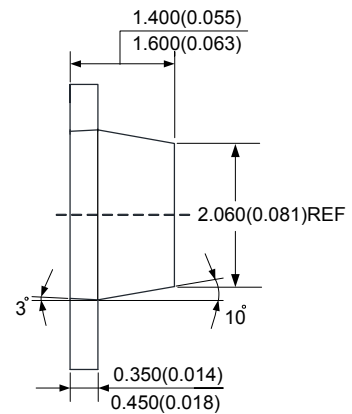
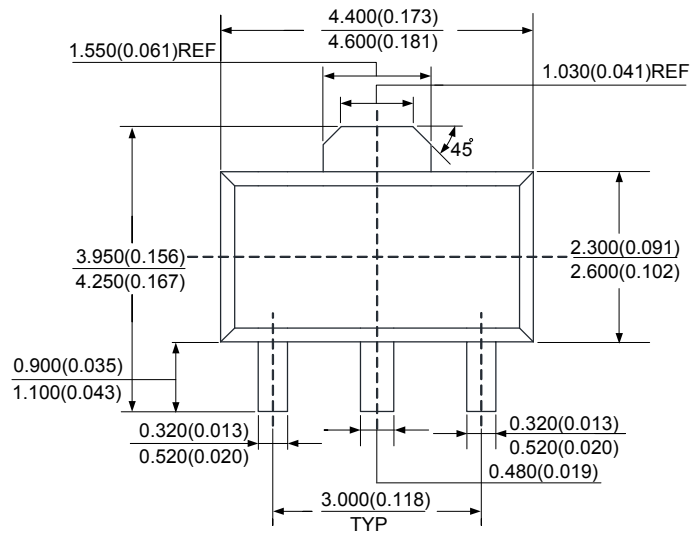
AZ1117B

Mechanical Dimensions

SOT-223

Unit: mm(inch)



**LOW DROPOUT LINEAR REGULATOR****AZ1117B****Mechanical Dimensions (Continued)****SOT-89****Unit: mm(inch)**

Part Obsolete



BCD Semiconductor Manufacturing Limited

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